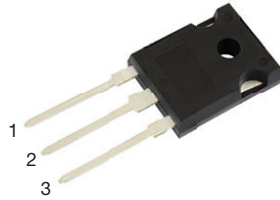
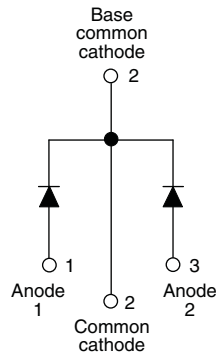


## Ultrafast Soft Recovery Diode, 2 x 30 A FRED Pt® Gen 4



TO-247AD 3L



### FEATURES

- Gen 4 FRED Pt® technology
- Low  $I_{RRM}$  and reverse recovery charge
- Very low forward voltage drop
- Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow  $V_F$ , soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 30 A
$V_R$	600 V
$V_F$ at $I_F$	1.19 V
$t_r$ typ.	See Recovery table
$T_J$ max.	175 °C
Package	TO-247AD 3L
Circuit configuration	Common cathode

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		600	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 131$ °C	30	A
Non-repetitive peak surge current, per leg	$I_{FSM}$	$T_C = 25$ °C, $t_p = 8.3$ ms, half sine wave	240	
Operating junction and storage temperature	$T_J, T_{Stg}$		-55 to +175	°C

ELECTRICAL SPECIFICATIONS ( $T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100$ $\mu$ A	600	-	-	V
Forward voltage	$V_F$	$I_F = 30$ A	-	1.36	1.6	
		$I_F = 60$ A	-	1.6	-	
		$I_F = 30$ A, $T_J = 125$ °C	-	1.23	-	
		$I_F = 60$ A, $T_J = 125$ °C	-	1.5	-	
		$I_F = 30$ A, $T_J = 150$ °C	-	1.19	1.35	
		$I_F = 60$ A, $T_J = 150$ °C	-	1.48	-	
Reverse leakage current	$I_R$	$V_R = V_R$ rated	-	-	50	$\mu$ A
		$T_J = 125$ °C, $V_R = V_R$ rated	-	-	500	
Junction capacitance	$C_T$	$V_R = 600$ V	-	18.3	-	pF



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	$I_F = 30\text{ A}$ $di_F/dt = 1000\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	-	65	-	ns
		$T_J = 125\text{ }^\circ\text{C}$		-	90	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^\circ\text{C}$		-	18	-	A
		$T_J = 125\text{ }^\circ\text{C}$		-	32	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^\circ\text{C}$		-	850	-	nC
		$T_J = 125\text{ }^\circ\text{C}$		-	1850	-	

<b>THERMAL - MECHANICAL SPECIFICATIONS</b>							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	$R_{thJC}$			-	-	1	$^\circ\text{C}/\text{W}$
Thermal resistance, case to heat sink	$R_{thCS}$			-	0.4	-	
Weight				-	6.0	-	g
				-	0.21	-	oz.
Mounting torque				6.0 (5)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AD 3L		C4PU3006L			

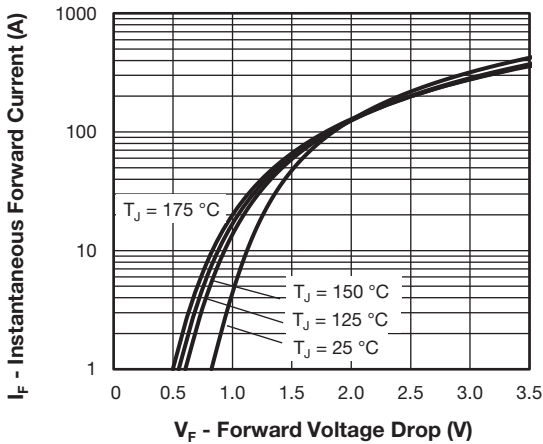


Fig. 1 - Typical Forward Voltage Drop Characteristics

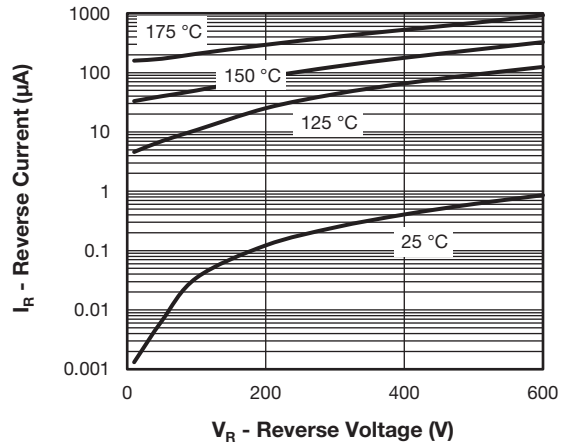


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

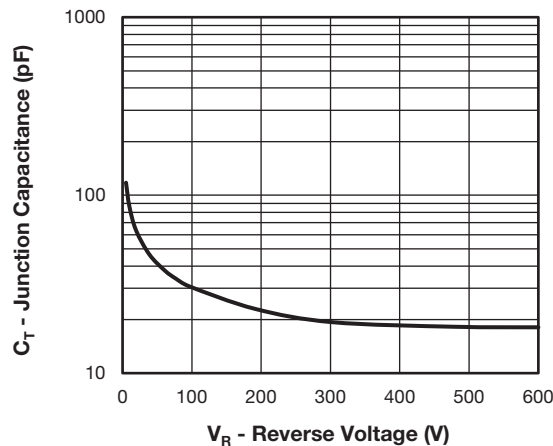


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

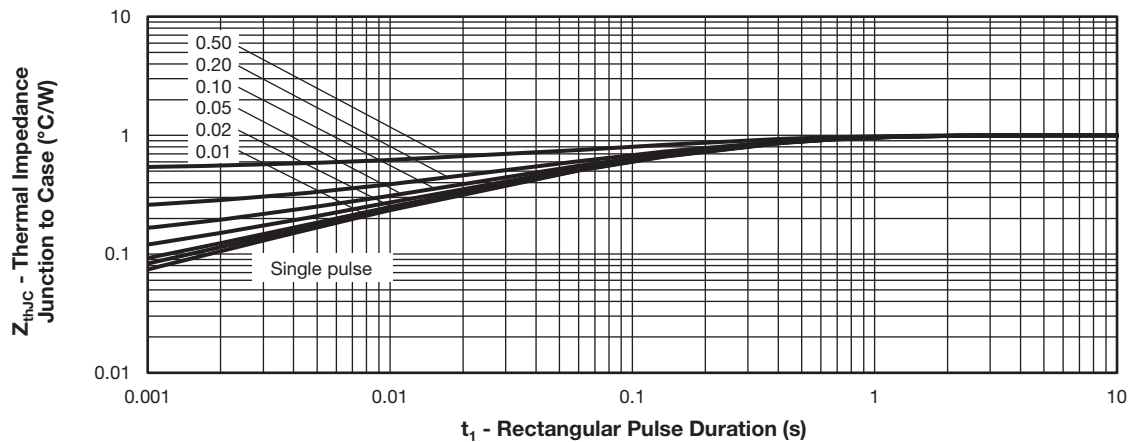


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

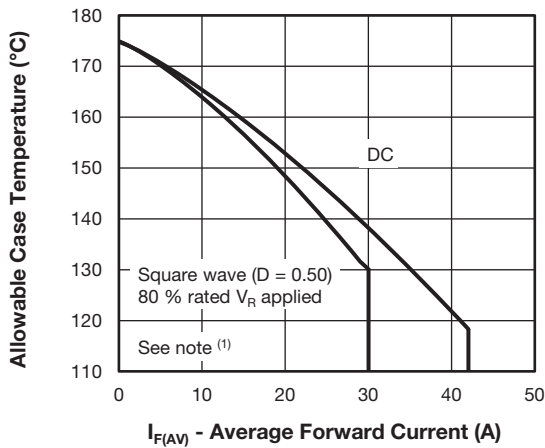


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

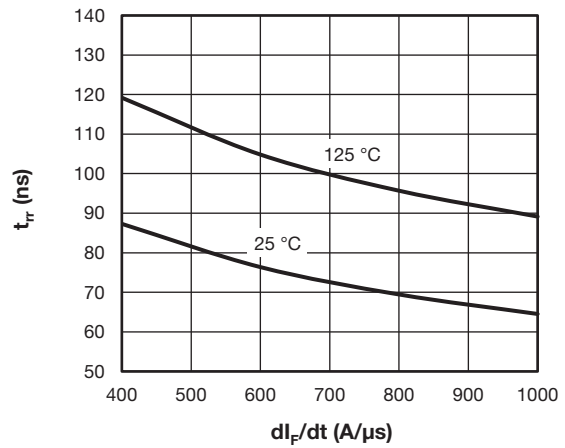


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$

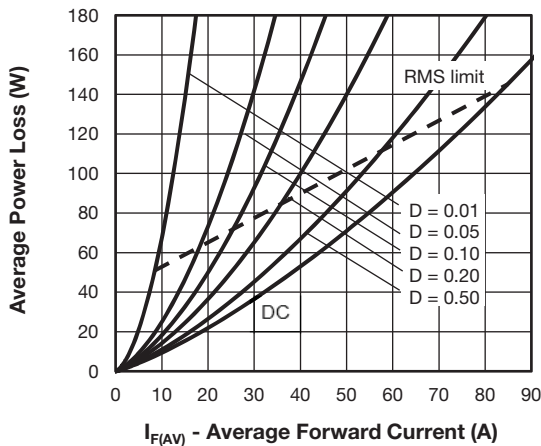


Fig. 6 - Forward Power Loss Characteristics

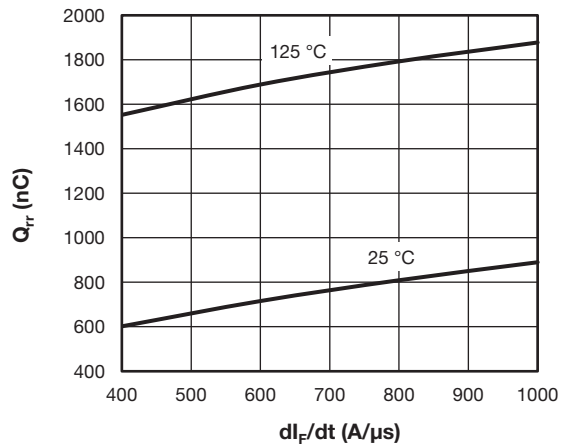


Fig. 8 - Typical Stored Charge vs.  $dI_F/dt$

**Note**

(1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see Fig.5)  
 $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_R$  = rated  $V_R$

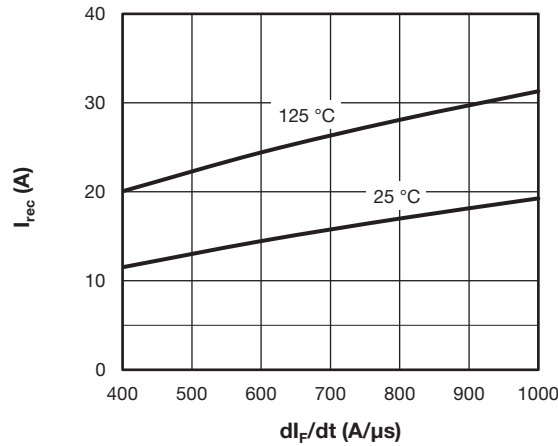


Fig. 9 - Typical Reverse Current vs. di/dt

**ORDERING INFORMATION TABLE**

Device code	<b>VS-</b>	<b>C</b>	<b>4</b>	<b>P</b>	<b>U</b>	<b>60</b>	<b>06</b>	<b>L</b>	<b>-N3</b>
	①	②	③	④	⑤	⑥	⑦	⑧	⑨

- 1** - Vishay Semiconductors product
- 2** - Circuit configuration:  
C = common diode
- 3** - FRED Pt Gen 4
- 4** - P = TO-247 package
- 5** - Process type:  
U = ultrafast recovery
- 6** - Current rating (60 = 2 x 30 A)
- 7** - Voltage rating (06 = 600 V)
- 8** - Package: L = long lead
- 9** - Environmental digit:  
-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

<b>ORDERING INFORMATION (Example)</b>			
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-C4PU6006L-N3	25	500	Antistatic plastic tube

<b>LINKS TO RELATED DOCUMENTS</b>		
Dimensions	TO-247AD 3L	<a href="http://www.vishay.com/doc?95626">www.vishay.com/doc?95626</a>
Part marking information	TO-247AD 3L	<a href="http://www.vishay.com/doc?95007">www.vishay.com/doc?95007</a>



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